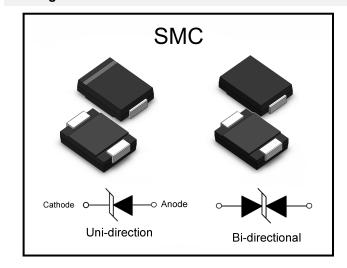


Transient Voltage Suppressor

Features

- · Excellent clamping capability
- Low leakage current
- · Low capacitance
- · High surge capability
- · Glass passivated chip
- · Epoxy resin package
- · Built-in strain relief
- · Will not fatigue
- RoHS Compliant
- "H" Prefix is for Automotive applications, AEC-Q101 qualified

Package



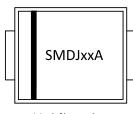
Mechanical Characteristics

- Package: SMC plastic package
- · Lead Finish: Matte Tin
- · Case Material: Epoxy Molding Compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020

Applications

- Telecom
- Computer
- · Industrial electronic
- · Consumer electronic
- · Automotive electronic

Making Code



Unidirection



Bidirection

Summary of Packing Options

Package	Packing Description	Packing Quantity	Industry Standard	
SMC	Tape/Reel,13" reel	3000	EIA-481-1	
	Tape/Reel,7" reel	500	EIA-481-1	

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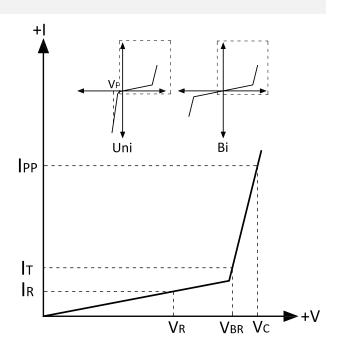




Transient Voltage Suppressor

Electrical Parameters

Parameter	Definition		
C.I	Junction Capacitance - typical capacitance		
OJ	measured with 0V or V _R bias		
1	Peak Pulse Current - maximum rated peak		
I _{PP}	impulse current		
Vc	Clamping Voltage - Peak voltage measured		
٧C	across the suppressor at a specified lppm		
V_{BR}	Breakdown Voltage - Maximum voltage that flows		
V BR	though the TVS at a specified test current (I_T)		
	Leakage Current - maximum peak off-state		
I _R	current measured at V _R		
V _R	Peak Off-state Voltage - maximum voltage		
۷R	that can be applied while maintaining off state		



Absolute Maximum Ratings (T_A=+25°C, unless otherwise noted)

Parameter	Symbol	Value	Units
Peak Pulse Power Dissipation(Note1,2)	P _{PPM}	3000	W
Steady State Power Dissipation (Note3)	P _D	6.5	W
Peak Forward Surge Current (Note4)	I _{FSM}	300	А
Maximum Instantaneous Forward Voltage at 100A (Note5)	V_{FM}	3.5/5	V
Typical Thermal Resistance Junction to Lead	R _{0JL}	15	°C/W
Typical Thermal Resistance Junction to Ambient	$R_{\theta JA}$	75	°C/W
Operating Junction Temperature Range	TJ	-55 to 150	°C
Storage Temperature Range	T _{STG}	-55 to 150	°C

Notes:

- (1) Non-repetitive current pulse, 10/1000us Waveform.
- (2) Mounted on copper pad area of 8×8mm to each terminal.
- (3) Infinite Heat Sink at T_A =50°C
- (4) Measured on 8.3ms single half sine wave or equivalent square wave, duty cycle=4 perminute maximum.
- (5) For UnidirectionalOnly, V_{FW} <3.5V for $V_{BR} \le 200V$ and V_{FM} <5.0V for $V_{BR} \ge 201V$.





Transient Voltage Suppressor

Absolute Maximum Ratings (T_A=+25°C, unless otherwise noted)

Part I	Number	Reverse Stand-Off Votage V _R	Vol	kdown tage (@ I _T	Test Current I _T	Maximum Clamping Voltage V _C @ I _{pp}	Maximum Peak Pulse Current	Maximum Reverse Leakage I _R @ V _R
(Uni)	(Bi)	(V)	Min.(V)	Max.(V)	(mA)	(V)	(A)	(uA)
SMDJ5.0A HSMDJ5.0A	SMDJ5.0CA HSMDJ5.0CA	5	6.4	7	10	9.2	326.1	800
SMDJ6.0A HSMDJ6.0A	SMDJ6.0CA HSMDJ6.0CA	6	6.67	7.37	10	10.3	291.3	800
SMDJ6.5A HSMDJ6.5A	SMDJ6.5CA HSMDJ6.5CA	6.5	7.22	7.98	10	11.2	267.9	500
SMDJ7.0A HSMDJ7.0A	SMDJ7.0CA HSMDJ7.0CA	7	7.78	8.6	10	12	250	200
SMDJ7.5A HSMDJ7.5A	SMDJ7.5CA HSMDJ7.5CA	7.5	8.33	9.21	1	12.9	232.6	100
SMDJ8.0A HSMDJ8.0A	SMDJ8.0CA HSMDJ8.0CA	8.0	8.89	9.83	1	13.6	220.6	50
SMDJ8.5A HSMDJ8.5A	SMDJ8.5CA HSMDJ8.5CA	8.5	9.44	10.4	1	14.4	208.3	20
SMDJ9.0A HSMDJ9.0A	SMDJ9.0CA HSMDJ9.0CA	9	10	11.1	1	15.4	194.8	10
SMDJ10A HSMDJ10A	SMDJ10CA HSMDJ10CA	10	11.1	12.3	1	17	176.5	5
SMDJ11A HSMDJ11A	SMDJ11CA HSMDJ11CA	11	12.2	13.5	1	18.2	164.8	2
SMDJ12A HSMDJ12A	SMDJ12CA HSMDJ12CA	12	13.3	14.7	1	19.9	150.8	2
SMDJ13A HSMDJ13A	SMDJ13CA HSMDJ13CA	13	14.4	15.9	1	21.5	139.5	2
SMDJ14A HSMDJ14A	SMDJ14CA HSMDJ14CA	14	15.6	17.2	1	23.2	129.3	2
SMDJ15A HSMDJ15A	SMDJ15CA HSMDJ15CA	15	16.7	18.5	1	24.4	123	2
SMDJ16A HSMDJ16A	SMDJ16CA HSMDJ16CA	16	17.8	19.7	1	26	115.4	2
SMDJ17A HSMDJ17A	SMDJ17CA HSMDJ17CA	17	18.9	20.9	1	27.6	108.7	2
SMDJ18A HSMDJ18A	SMDJ18CA HSMDJ18CA	18	20	22.1	1	29.2	102.7	2

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Transient Voltage Suppressor

Absolute Maximum Ratings (T_A=+25°C, unless otherwise noted)

Part N	Number	Reverse Stand-Off Votage V _R	Vol	kdown tage @ I _T	Test Current I _T	Maximum Clamping Voltage V _C @ I _{PP}	Maximum Peak Pulse Current	Maximum Reverse Leakage I _R @ V _R
(Uni)	(Bi)	(V)	Min.(V)	Max.(V)	(mA)	(V)	(A)	(uA)
SMDJ20A HSMDJ20A	SMDJ20CA HSMDJ20CA	20	22.2	24.5	1	32.4	92.6	2
SMDJ22A HSMDJ22A	SMDJ22CA HSMDJ22CA	22	24.4	26.9	1	35.5	84.5	2
SMDJ24A HSMDJ24A	SMDJ24CA HSMDJ24CA	24	26.7	29.5	1	38.9	77.1	2
SMDJ26A HSMDJ26A	SMDJ26CA HSMDJ26CA	26	28.9	31.9	1	42.1	71.3	2
SMDJ28A HSMDJ28A	SMDJ28CA HSMDJ28CA	28	31.1	34.4	1	45.4	66.1	2
SMDJ30A HSMDJ30A	SMDJ30CA HSMDJ30CA	30	33.3	36.8	1	48.4	62	2
SMDJ33A HSMDJ33A	SMDJ33CA HSMDJ33CA	33	36.7	40.6	1	53.3	56.3	2
SMDJ36A HSMDJ36A	SMDJ36CA HSMDJ36CA	36	40	44.2	1	58.1	51.6	2
SMDJ40A HSMDJ40A	SMDJ40CA HSMDJ40CA	40	44.4	49.1	1	64.5	46.5	2
SMDJ43A HSMDJ43A	SMDJ43CA HSMDJ43CA	43	47.8	52.8	1	69.4	43.2	2
SMDJ45A HSMDJ45A	SMDJ45CA HSMDJ45CA	45	50	55.3	1	72.7	41.3	2
SMDJ48A HSMDJ48A	SMDJ48CA HSMDJ48CA	48	53.33	58.9	1	77.4	38.8	2
SMDJ51A HSMDJ51A	SMDJ51CA HSMDJ51CA	51	56.7	62.7	1	82.4	36.4	2
SMDJ58A HSMDJ58A	SMDJ58CA HSMDJ58CA	58	64.4	71.2	1	93.6	32.1	2
SMDJ60A HSMDJ60A	SMDJ60CA HSMDJ60CA	60	66.7	73.7	1	96.8	31	2
SMDJ64A HSMDJ64A	SMDJ64CA HSMDJ64CA	64	71.1	78.6	1	103	29.1	2
SMDJ70A HSMDJ70A	SMDJ70CA HSMDJ70CA	70	78.8	86	1	113	26.5	2

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Transient Voltage Suppressor

Absolute Maximum Ratings (T_A=+25°C, unless otherwise noted)

Part N	lumber	Reverse Stand-Off Votage V _R	Vol	kdown tage @ I _T	Test Current I _T	Maximum Clamping Voltage V _C @ I _{pp}	Maximum Peak Pulse Current Ipp	Maximum Reverse Leakage I _R @ V _R
(Uni)	(Bi)	(V)	Min.(V)	Max.(V)	(mA)	(V)	(A)	(uA)
SMDJ75A HSMDJ75A	SMDJ75CA HSMDJ75CA	75	83.3	92.1	1	121	24.8	2
SMDJ78A HSMDJ78A	SMDJ78CA HSMDJ78CA	78	86.7	95.8	1	126	23.8	2
SMDJ85A HSMDJ85A	SMDJ85CA HSMDJ85CA	85	94.4	104	1	137	21.9	2
SMDJ90A HSMDJ90A	SMDJ90CA HSMDJ90CA	90	100	111	1	146	20.5	2
SMDJ100A HSMDJ100A	SMDJ100CA HSMDJ100CA	100	111	123	1	162	18.5	2
SMDJ110A HSMDJ110A	SMDJ110CA HSMDJ110CA	110	122	135	1	177	16.9	2
SMDJ120A HSMDJ120A	SMDJ120CA HMDJ120CA	120	133	147	1	193	15.5	2
SMDJ130A HSMDJ130A	SMDJ130CA HSMDJ130CA	130	144	159	1	209	14.4	2
SMDJ150A HSMDJ150A	SMDJ150CA HSMDJ150CA	150	167	185	1	243	12.3	2
SMDJ160A HSMDJ160A	SMDJ160CA HSMDJ160CA	160	178	197	1	259	11.6	2
SMDJ170A HSMDJ170A	SMDJ170CA HSMDJ170CA	170	189	209	1	275	10.9	2
SMDJ180A HSMDJ180A	SMDJ180CA HSMDJ180CA	180	198	230.4	1	292	10.3	2
SMDJ220A HSMDJ220A	SMDJ220CA HSMDJ220CA	220	242	281.6	1	356	8.4	2





Transient Voltage Suppressor

Ratings and Characteristic Curves (T_A=+25°C, unless otherwise noted)

Figure 1: Peak Pulse Power Rating



Figure 3: Pulse Waveform

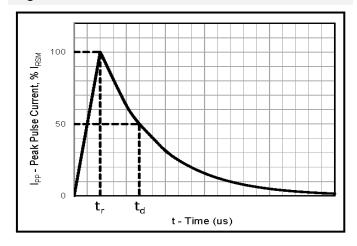


Figure 5: Steady State Power Dissipation Derating

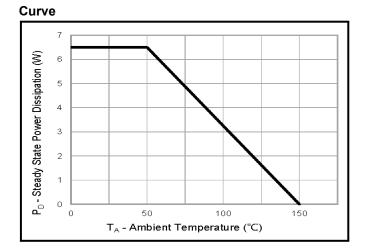


Figure 2: Pulse Derating Curve

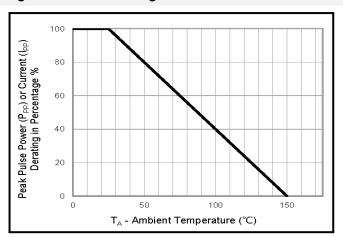


Figure 4: Typical Junction Capacitance

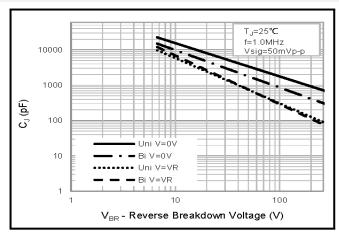
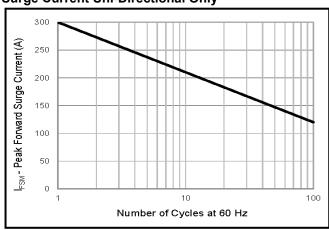


Figure 6: Maximum Non-Repetitive Peak Forward





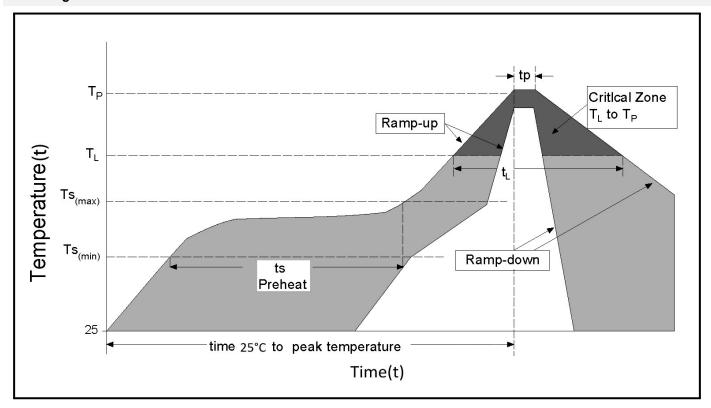






Transient Voltage Suppressor

Soldering Parameters



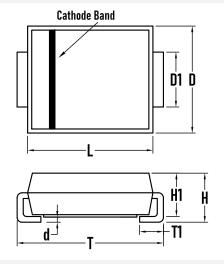
Reflow 0	Lead-free assembly			
	- Temperature Min (T _S (min))	150°C		
Pre Heat	- Temperature Max (T _S (max))	200°C		
	- Time (min to max) (t _S)	60 - 180 secs		
Average ramp up rate (Lic	quidus Temp (T _L) to peak)	3°C/second max		
$T_{S}(max)$ to T_{L} -	T _S (max) to T _L - Ramp-up Rate			
Reflow	- Temperature (T _L) (Liquidus)	217°C		
Kellow	- Time (t _L)	60 -150 secs		
Peak Temp	Peak Temperature (T _P)			
Time within 5°C of actua	Time within 5°C of actual peak Temperature (t _p)			
Ramp-do	6°C/second max			
Time 25°C to pea	Time 25°C to peak Temperature (t)			
Do not	260°C			

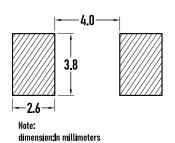




Transient Voltage Suppressor

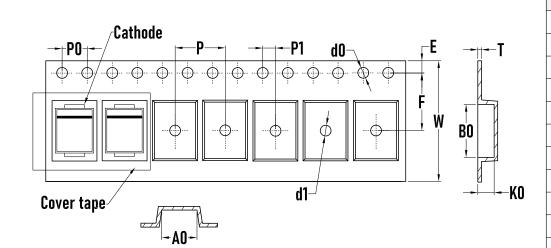
Package Mechanical Data - SMC





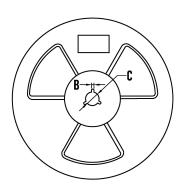
SYMBOL	MILLIN	IETER	Inches		
STIVIDOL	MIN	MAX	MIN	MAX	
D	5.5	6.1	0.217	0.240	
D1	2.7	3.3	0.106	0.130	
Т	7.4	8.4	0.291	0.331	
T1	0.8	1.6	0.031	0.063	
d	_	0.3	-	0.012	
H1	2.0	2.6	0.079	0.102	
Н	2.1	2.7	0.083	0.106	
L	6.5	7.1	0.256	0.280	

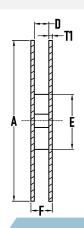
Packaging Tape - SMC



SYMBOL	MILLIMETER
A0	6.00±0.1
В0	8.25±0.02
d0	1.50±0.1
d1	1.50±0.1
Е	1.75±0.1
F	7.50±0.1
K0	2.70±0.1
Р	8.00±0.1
P0	4.00±0.1
P1	2.00±0.05
W	16.00±0.1
T	0.22±0.02

Packaging Reel





SYMBOL	MILLIMETER
Α	323±2
В	3.0±0.2
С	15.0±0.5
D	16±2
E	73±2
T1	2.2±0.2
Quantity	3000PCS

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